

2SB1434

Silicon PNP epitaxial planer type

For low-frequency output amplification

Complementary to 2SD2177

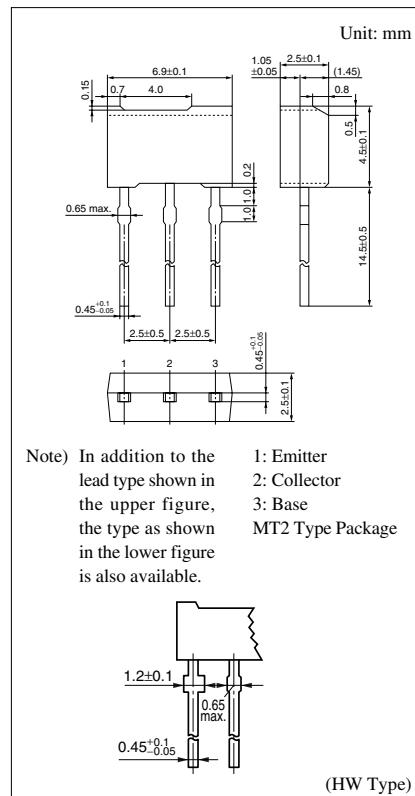
■ Features

- Low collector to emitter saturation voltage $V_{CE(sat)}$
- Allowing supply with the radial taping

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|-------------------------------|-----------|-------------|------------------|
| Collector to base voltage | V_{CBO} | -50 | V |
| Collector to emitter voltage | V_{CEO} | -50 | V |
| Emitter to base voltage | V_{EBO} | -5 | V |
| Peak collector current | I_{CP} | -3 | A |
| Collector current | I_C | -2 | A |
| Collector power dissipation * | P_C | 1 | W |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

Note) *: Printed circuit board: Copper foil area of 1 cm^2 or more, and the board thickness of 1.7 mm for the collector portion



■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--|-------------------------|--|-----|-------|------|---------------|
| Collector cutoff current | I_{CBO} | $V_{CB} = -20 \text{ V}, I_E = 0$ | | | -0.1 | μA |
| Collector to base voltage | V_{CBO} | $I_C = -10 \mu\text{A}, I_E = 0$ | -50 | | | V |
| Collector to emitter voltage | V_{CEO} | $I_C = -1 \text{ mA}, I_B = 0$ | -50 | | | V |
| Emitter to base voltage | V_{EBO} | $I_E = -10 \mu\text{A}, I_C = 0$ | -5 | | | V |
| Forward current transfer ratio * ¹ | h_{FE1} ^{*2} | $V_{CE} = -2 \text{ V}, I_C = -200 \text{ mA}$ | 120 | | 340 | |
| | h_{FE2} | $V_{CE} = -2 \text{ V}, I_C = -1 \text{ A}$ | 60 | | | |
| Collector to emitter saturation voltage * ¹ | $V_{CE(sat)}$ | $I_C = -1 \text{ A}, I_B = -50 \text{ mA}$ | | -0.2 | -0.3 | V |
| Base to emitter saturation voltage * ¹ | $V_{BE(sat)}$ | $I_C = -1 \text{ A}, I_B = -50 \text{ mA}$ | | -0.85 | -1.2 | V |
| Transition frequency | f_T | $V_{CB} = -10 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$ | | 110 | | MHz |
| Collector output capacitance | C_{ob} | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ | | 40 | 60 | pF |

Note) *1: Pulse measurement

*2: Rank classification

| Rank | R | S | No-rank |
|-----------|------------|------------|------------|
| h_{FE1} | 120 to 240 | 170 to 340 | 120 to 340 |

Product of no-rank is not classified and have no indication for rank.

